Technical Data Data Sheet N0702, Rev. - **Green Products**

48CTQ060/48CTQ060S /48CTQ060-1 SCHOTTKY RECTIFIER

Applications:

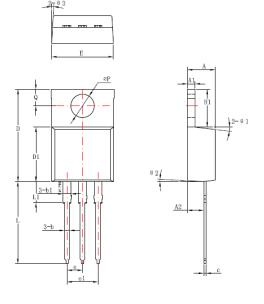
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In Inches / mm



Symbol	millimeters			
Cymber	Min Typical		Max	
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
e		2.54		
e1		5.06		
H1	6.04	6.24	6.44	
L	12.7	13.56	13.78	
L1		3.5		
ΦР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		

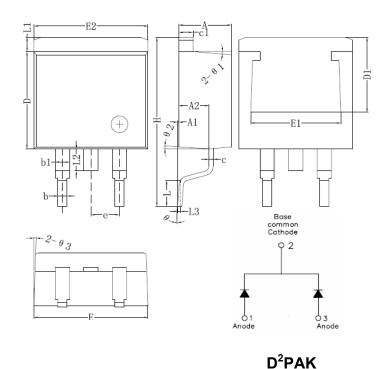
Dimensions in

TO-220AB

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 📱 (86) 25-87123907 •

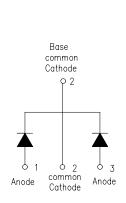
[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

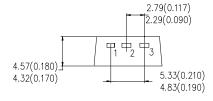
Technical Data Data Sheet N0702, Rev. - **Green Products**



	D	Dimensions in			
Symbol	millimeters				
-	Min.	Typical	Max.		
Α	4.55	4.70	4.85		
A1	0	0.10	0.25		
A2	2.59	2.69	2.89		
b	0.71	0.81	0.96		
b1		1.27			
С	0.36	0.38	0.61		
c1	1.17	1.27	1.37		
D	8.55	8.70	8.85		
D1	6.40				
E	10.01	10.16	10.31		
E1	7.6				
E2	9.98	10.08	10.18		
е		2.54			
Н	14.6	15.1	15.6		
L	2.00	2.30	2.70		
L1	1.17	1.27	1.40		
L2			2.20		
L3		0.25BSC			
е	0	-	8°		
e1		5°			
e2		4°			
e3		4°			

_1.32(0.052) 1.22(0.048) _10.54(0.415)_ 10.29(0.405) 1.40 (0.055) MAX. 8.76 (0.345) 8.61 (0.339) 24.25(0.955) 23.47(0.924) 3.96(0.156) 3.55(0.140) 14.09(0.555) 13.47(0.530) - 0.10(0.004) 1.40(0.055) 0.94(0.037) 2.89(0.114) 1.15(0.045) 2.64(0.104) 0.69(0.027)





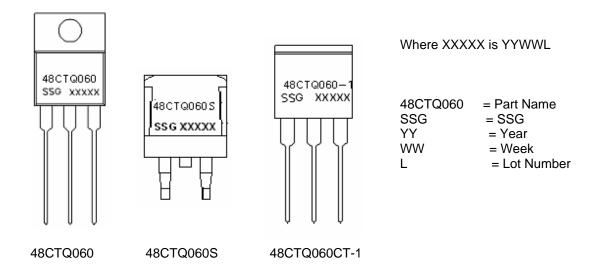
TO-262

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

Technical Data Data Sheet N0702, Rev. - **Green Products**

Marking Diagram:



Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
48CTQ060	TO-220AB (Pb-Free)	50pcs / tube
48CTQ060S	D ² PAK (Pb-Free)	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	60	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =111°C, rectangular wave form	40	Α
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	310	А

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

Technical Data Data Sheet N0702, Rev. - Green Products

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
	V_{F1}	@ 20A, Pulse, T _J = 25 °C	0.61	V
Max. Forward Voltage Drop		@ 40A, Pulse, T _J = 25 °C	0.83	
*	V_{F2}	@ 20A, Pulse, T _J = 125 °C	0.58	V
		@ 40A, Pulse, T _J = 125 °C	0.75	
Max. Reverse Current at DC	I_{R1}	$@V_R = rated V_R$	2	mA
condition		T _J = 25 °C		
Max. Reverse Current	I _{R2}	$@V_R = rated V_R$	89	mA
		T _J = 125 °C		
Max. Junction Capacitance	C_T	$@V_R = 5V, T_C = 25 °C$	1220	pF
		f _{SIG} = 1MHz		
Typical Series Inductance	L _S	Measured lead to lead 5 mm from	8.0	nΗ
		package body		
Max. Voltage Rate of	dv/dt	-	10,000	V/μs
Change(Rated V _R)				

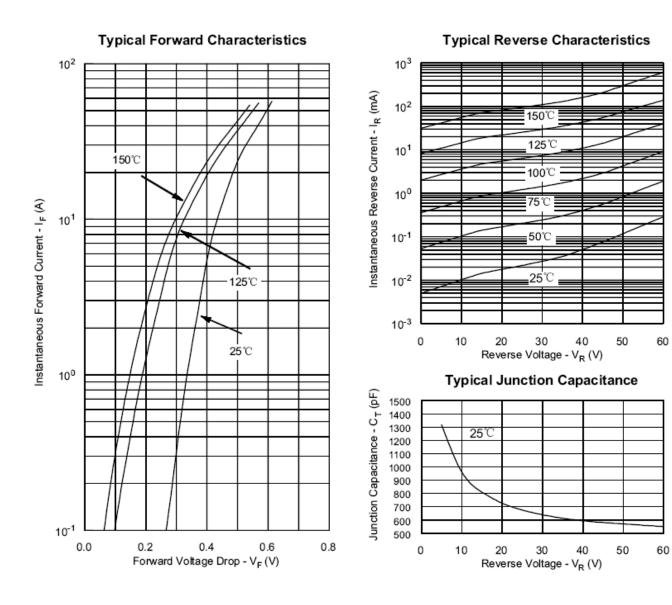
Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-55 to +150	°C
Max. Storage Temperature	T_{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ heta JC}$	DC operation	2.0	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{\theta cs}$	Mounting surface, smooth and greased	0.50	°C/W
Approximate Weight	wt	-	2	g
Case Style	TO-220AB,D ² PAK,TO-262(Suffix"s"for D ² PAK; Suffix"-1"for TO-262)			

 [•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 ☐ (86) 25-87123907 •
 • FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

Technical Data Data Sheet N0702, Rev. - **Green Products**



[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 📱 (86) 25-87123907 •

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



Technical Data Data Sheet N0702, Rev. - **Green Products**

DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- . 4- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..